

Loopback strobe LBDQS to Loopback data LBDQ relationship is illustrated in Figure 203.

- tLBQSH describes the single-ended LBDQS strobe high pulse width
- tLBQSL describes the single-ended LBDQS strobe low pulse width
- tLBDQSQ describes the latest valid transition of LBDQ measured at both rising and falling edges of LBDQS
- tLBQH describes the earliest invalid transition of LBDQ measured at both rising and falling edges of LBDQS
- tLBDVW describes the data valid window per device per UI and is derived from (tLBQH-tLBDQSQ) of each UI on a given DRAM

Speed	DDR5-3200	DDR5-3600	DDR5-4000	DDR5-4400	DDR5-4800
-------	-----------	-----------	-----------	-----------	-----------

Speed		DDR5-3200		DDR5-3600		DDR5-4000		DDR5-4400		DDR5-4800		Units	NOTE
Parameter	Symbol	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
Loopback Timing													
Loopback LBDQS Output Low Time	tLBQSL	0.7	-	0.7	-	0.7	-	0.7	-	0.7	-	tCK	1
Loopback LBDQS Output High Time	tLBQSH	0.7	-	0.7	-	0.7	-	0.7	-	0.7	-	tCK	1
Loopback LBDQS to LBDQ Skew	tLBDQSQ	0.2	-	0.2	-	0.2	-	0.2	-	0.2	-	tCK/2	1
Loopback LBDQ Output Time from LBDQS	tLBQH	3.6	-	3.6	-	3.6	-	3.6	-	3.6	-	tCK/2	1
Loopback Data valid window (tLBQH-tLBDQSQ) of each UI per DRAM	tLBDVW	3.4	-	3.4	-	3.4	-	3.4	-	3.4	-	tCK/2	1
NOTE 1 Based on Loopback 4-way interleave setting (see Section 3.5.54)													

Speed	DDR5-5200	DDR5-5600	DDR5-6000	DDR5-6400
-------	-----------	-----------	-----------	-----------

Speed		DDR5-5200		DDR5-5600		DDR5-6000		DDR5-6400		Units	NOTE
Parameter	Symbol	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
Loopback Timing											
Loopback LBDQS Output Low Time	tLBQSL	TBD	-	TBD	-	TBD	-	TBD	-	tCK	1
Loopback LBDQS Output High Time	tLBQSH	TBD	-	TBD	-	TBD	-	TBD	-	tCK	1
Loopback LBDQS to LBDQ Skew	tLBDQSQ	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1
Loopback LBDQ Output Time from LBDQS	tLBQH	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1
Loopback Data valid window (tLBQH-tLBDQSQ) of each UI per DRAM	tLBDVW	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1
NOTE 1 Based on Loopback 4-way interleave setting (see Section 3.5.54)											

9.3 Loopback Output Timing (Cont'd)

Table 441 — Loopback Output Timing Parameters for DDR5-6800 to 8400

Speed		DDR5-6800		DDR5-7200		DDR5-7600		DDR5-8000		DDR5-8400		Units	NOTE
Parameter	Symbol	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
Loopback Timing													
Loopback LBDQS Output Low Time	tLBQSL	TBD	-	TBD	-	TBD	-	TBD	-	TBD	-	tCK	1
Loopback LBDQS Output High Time	tLBQSH	TBD	-	TBD	-	TBD	-	TBD	-	TBD	-	tCK	1
Loopback LBDQS to LBDQ Skew	tLBDQSQ	TBD	-	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1
Loopback LBDQ Output Time from LBDQS	tLBQH	TBD	-	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1
Loopback Data valid window (tLBQH-tLBDQSQ) of each UI per DRAM	tLBDVW	TBD	-	TBD	-	TBD	-	TBD	-	TBD	-	tCK/2	1

Note(s):

1: Based on Loopback 4-way interleave setting (see MR53)

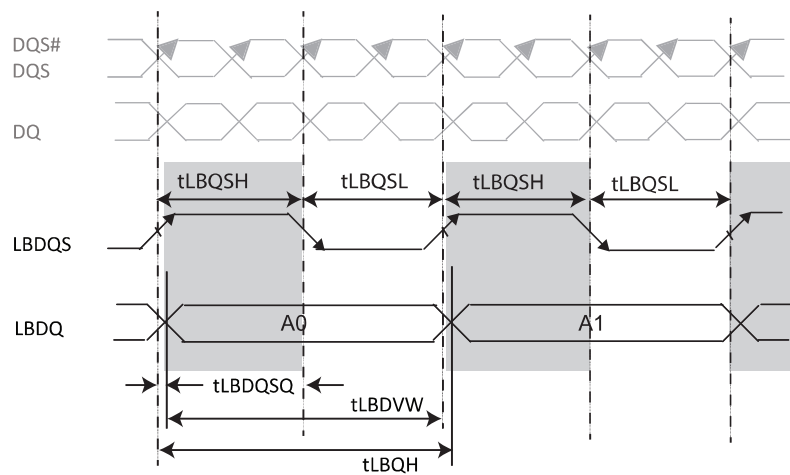


Figure 203 — Loopback Strobe to Data Relationship

LIGHT GREY - All Light Grey text is defined as something that should be considered TBD. The content may be accurate or the same as previous technologies but has not yet been reviewed or determined to be the working assumption.

9.3.1 Alert_n Output Drive Characteristic

A functional representation of the output buffer is shown in Figure 204. Output driver impedance RON is defined as follows:

$$RON_{Pd} = \frac{V_{out}}{|I_{out}|} \text{ under the condition that } RON_{Pu} \text{ is off}$$

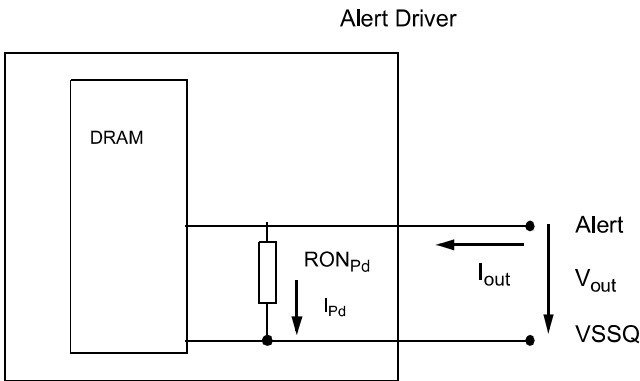


Figure 204 — Output Buffer Function

Table 442 — RON_{Pd} Vout Values

Resistor	Vout	Min	Max	Unit	NOTE
RON _{Pd}	VOLdc= 0.1* VDDQ	0.3	1.1	R _{ZQ} /7	
	V _{OMdc} = 0.8* VDDQ	0.4	1.1	R _{ZQ} /7	
	V _{OHdc} = 0.95* VDDQ	0.4	1.25	R _{ZQ} /7	

9.3.2 Output Driver Characteristic of Connectivity Test (CT) Mode

Following Output driver impedance RON will be applied to the Test Output Pin during Connectivity Test (CT) Mode.

The individual pull-up and pull-down resistors (RONPu_CT and RONPd_CT) are defined as follows:

$$RON_{Pu_CT} = \frac{V_{DDQ} - V_{OUT}}{|I_{out}|}$$

$$RON_{Pd_CT} = \frac{V_{OUT}}{|I_{out}|}$$

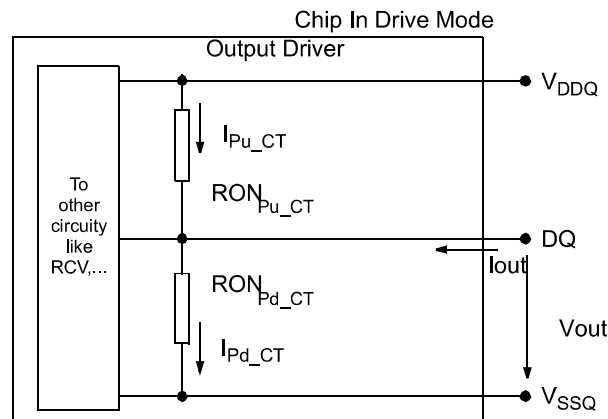


Figure 205 — Output Driver

Table 443 — RONNOM_CT Vout Values

RONNOM_CT	Resistor	Vout	Max	Units	NOTE
34Ω	RONPd_CT	VOBdc = 0.2 x VDDQ	1.9	RZQ/7	1,2
		VOLdc = 0.5 x VDDQ	2.0	RZQ/7	1,2
		VOMdc = 0.8 x VDDQ	2.2	RZQ/7	1,2
		VOHdc = 0.95 x VDDQ	2.5	RZQ/7	1,2
	RONPu_CT	VOBdc = 0.2 x VDDQ	1.9	RZQ/7	1,2
		VOLdc = 0.5 x VDDQ	2.0	RZQ/7	1,2
		VOMdc = 0.8 x VDDQ	2.2	RZQ/7	1,2
		VOHdc = 0.95 x VDDQ	2.5	RZQ/7	1,2
NOTE 1 Connectivity test mode uses un-calibrated drivers, showing the full range over PVT. No mismatch between pull up and pull down is defined.					
NOTE 2 Uncalibrated drive strength tolerance is specified at +/- 30%					